

## 2PA1576

# PNP general-purpose transistor Rev. 06 — 17 November 2009

Product data sheet

## **Product profile**

#### 1.1 General description

PNP transistor in a SOT323 (SC-70) plastic package. The NPN complement is 2PC4081.

#### 1.2 Features

- Low current (max. 150 mA)
- Low voltage (max. 50 V)
- Low collector capacitance (typ. 2.5 pF)

#### 1.3 Applications

General-purpose switching and amplification

#### 2. **Pinning information**

Table 1. **Pinning** 

Pin	Description	Simplified outline	Symbol
1	base	_	_
2	emitter	<u> </u>	3 
3	collector	1 2	1 —
			sym013

#### **Ordering information** 3.

**Ordering information** Table 2.

Type number	Package	Package				
	Name	Description	Version			
2PA1576Q	SC-70	plastic surface mounted package; 3 leads	SOT323			
2PA1576R						
2PA1576S						



#### **PNP** general-purpose transistor

## 4. Marking

Table 3. Marking codes

Type number	Marking code <sup>[1]</sup>
2PA1576Q	F*Q
2PA1576R	F*R
2PA1576S	F*S

<sup>[1] \* = -:</sup> made in Hong Kong

## 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-60	V
$V_{CEO}$	collector-emitter voltage	open base	-	<b>-50</b>	V
$V_{EBO}$	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current (DC)		-	-150	mA
I <sub>CM</sub>	peak collector current		-	-200	mA
I <sub>BM</sub>	peak base current		-	-200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> -	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

## 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>[1]</u> -	-	625	K/W

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

<sup>\* =</sup> t: made in Malaysia

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## **Characteristics**

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Table 6. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Parameter	Conditions	Min	Тур	Max	Unit
collector-base cut-off current	$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V}$	-	-	-100	nA
	$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V};$ $T_j = 150 \text{ °C}$	-	-	<b>-</b> 5	μΑ
emitter-base cut-off current	$I_C = 0 A; V_{EB} = -4 V$	-	-	-100	nA
DC current gain	$I_C = -1 \text{ mA}; V_{CE} = -6 \text{ V}$				
2PA1576Q		120	-	270	
2PA1576R		180	-	390	
2PA1576S		270	-	560	
collector-emitter saturation voltage	$I_C = -50 \text{ mA};$ $I_B = -5 \text{ mA}$	[1] -	-	-500	mV
collector capacitance	$I_E = i_e = 0 \text{ A};$ $V_{CB} = -12 \text{ V}; f = 1 \text{ MHz}$	-	2.5	3.5	pF
transition frequency	$I_C = -2 \text{ mA};$ $V_{CE} = -12 \text{ V};$ f = 100  MHz	100	-	-	MHz
	collector-base cut-off current  emitter-base cut-off current  DC current gain  2PA1576Q  2PA1576R  2PA1576S  collector-emitter saturation voltage  collector capacitance  transition	$ \begin{array}{lll} \text{collector-base} & I_E = 0 \text{ A; } V_{CB} = -30 \text{ V} \\ I_E = 0 \text{ A; } V_{CB} = -30 \text{ V; } \\ I_E = 0 \text{ A; } V_{CB} = -30 \text{ V; } \\ I_T = 150 \text{ °C} \\ \end{array} $ emitter-base cut-off current $ \begin{array}{lll} I_C = 0 \text{ A; } V_{EB} = -4 \text{ V} \\ \end{array} $ $ \begin{array}{lll} I_C = 0 \text{ A; } V_{EB} = -4 \text{ V} \\ \end{array} $ $ \begin{array}{lll} I_C = -1 \text{ mA; } V_{CE} = -6 \text{ V} \\ \end{array} $ $ \begin{array}{lll} I_C = -1 \text{ mA; } V_{CE} = -6 \text{ V} \\ \end{array} $ $ \begin{array}{lll} I_C = -1 \text{ mA; } I_C = -5 \text{ V} \\ \end{array} $ $ \begin{array}{lll} I_C = -50 \text{ mA; } \\ I_B = -5 \text{ mA} \\ \end{array} $ $ \begin{array}{lll} I_C = -50 \text{ mA; } \\ I_C = -50 \text{ mA; } \\ \end{array} $ $ \begin{array}{lll} I_C = -12 \text{ V; } I_C = 1 \text{ MHz} \\ \end{array} $ $ \begin{array}{lll} I_C = -12 \text{ V; } I_C = -12  V$	$ \begin{array}{llllllllllllllllllllllllllllllllllll$	$ \begin{array}{c} \text{collector-base} \\ \text{cut-off current} \\ \hline \\ I_E = 0 \text{ A; } V_{CB} = -30 \text{ V} \\ \hline \\ I_E = 0 \text{ A; } V_{CB} = -30 \text{ V; } \\ \hline \\ T_j = 150 \text{ °C} \\ \hline \\ \text{emitter-base} \\ \text{cut-off current} \\ \hline \\ DC \text{ current gain} \\ \hline \\ DC \text{ current gain} \\ \hline \\ I_C = -1 \text{ mA; } V_{CE} = -6 \text{ V} \\ \hline \\ 2PA1576Q \\ \hline \\ 2PA1576R \\ \hline \\ 2PA1576S \\ \hline \\ 2PA1576S \\ \hline \\ 2PA 1576S \\ \hline \\ collector-emitter \\ \text{saturation } \\ voltage \\ \hline \\ \text{collector} \\ \hline \\ collector \\ \hline \\ capacitance \\ \hline \\ V_{CB} = -12 \text{ V; } f = 1 \text{ MHz} \\ \hline \\ \text{transition } \\ \hline \\ I_C = -2 \text{ mA; } \\ \hline \\ V_{CE} = -12 \text{ V; } \\ \hline \end{array} $	$ \begin{array}{c} \text{collector-base} \\ \text{cut-off current} \\ \hline \\ I_E = 0 \text{ A; } V_{CB} = -30 \text{ V;} \\ \hline \\ I_E = 0 \text{ A; } V_{CB} = -30 \text{ V;} \\ \hline \\ T_j = 150 \text{ °C} \\ \hline \\ \\ \text{emitter-base} \\ \text{cut-off current} \\ \hline \\ DC \text{ current gain} \\ \hline \\ DC \text{ current gain} \\ \hline \\ I_C = -1 \text{ mA; } V_{CE} = -6 \text{ V} \\ \hline \\ 2PA1576Q \\ \hline \\ 2PA1576R \\ \hline \\ 2PA1576S \\ \hline \\ 2PA1576S \\ \hline \\ 2PA1576S \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

## 8. Package outline

#### Plastic surface-mounted package; 3 leads **SOT323** В Α X $H_{\mathsf{E}}$ = v (M) A Q **→** w M B е detail X 2 mm scale **DIMENSIONS** (mm are the original dimensions) UNIT D С Ε Q bp e<sub>1</sub> ΗE Lp w max 0.4 0.25 2.2 1.35 0.23 0.1 1.3 0.65 0.2 0.2 mm 0.8 0.3 0.10 1.15 0.15 REFERENCES **EUROPEAN** OUTLINE **ISSUE DATE** PROJECTION VERSION IEC **JEDEC JEITA** 04-11-04 SOT323 SC-70 06-03-16

Fig 1. Package outline SOT323 (SC-70)

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## 9. Revision history

#### Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
2PA1576	20091117	Product data sheet	-	2PA1576_5
Modifications:	including new content.	eet was changed to reflect the legal definitions and disclate chage outline SOT323 (SC-7	imers. No changes w	
2PA1576_5	20041124	Product data sheet	-	2PA1576_4
2PA1576_4	19990531	Product specification	-	2PA1576_3
2PA1576_3	19970328	Objective specification	-	2PA1576_2
2PA1576_2	19931213	n.a.	-	n.a.

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## 10. Legal information

#### 10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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